

### KSC5803

### High Voltage Color Display Horizontal Deflection Output (No Damper Diode)

eHigh Breakdown Voltage : BV=1500V •High Speed Switching : t=0.41s டிTyp.)

•Wide S.O.A

•For C-Monitor(85KHz)



## **NPN Triple Diffused Planar Silicon Transistor**

### Absolute Maximum Ratingsoted

Symbol	Parameter	Value	Units
VCBO	Collector-Base Voltage	1500	V
VCEO	Collector-Emitter Voltage	800	V
VEBO	Emitter-Base Voltage	6	V
IC	Collector Current (DC)	12	Α
ICP	Collector Current (Pulse)	24	Α
PC	Collector Dissipation (TC=25°C)	70	W
TJ	Junction Temperature	150	-C
TSTG	Storage Temperature	- 55 ~ 150	€C

### Electrical Characteristics vise noted

Symbol	Pa	rameterTest Condition	Min.	Тур.	Max.	U nit
ICES	Collector Cut-off Current VCE = 1400V,	VBE=0			1	<b>s</b> mA
ICBO	Collector Cut-off CurrentVCE= 800V, IE	= 0			10	μΑ
IEBO	Emitter Cut-off CurrentVEB = 4V, IC = 0				1	mA
hFE1 hFE2	DC Current GainVCE = 5V, IC = 1A VCE = 5V, IC = 8A		15 5.		40 8.5	
VCE(sat)	Collector-Emitter Saturation VoltageIC		5		3	V
VBE(sat)	Base-Emitter Saturation VoltageIC = 8/	, IB = 2A			1.5	V
tSTG	Storage TimeVCC = 200V, IC = 7A Fall TimeIB1 = 1.4A, IB2= - 2.8A				4	J\$
tF	RL = $28.6\Omega$				0.3	ļ\$

## **Typical Characteristics**

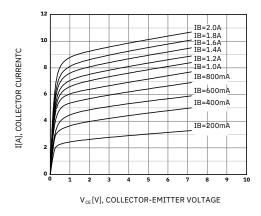


Figure 1. Static Characteristic

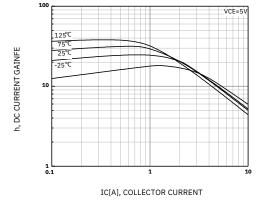


Figure 2. DC current Gain

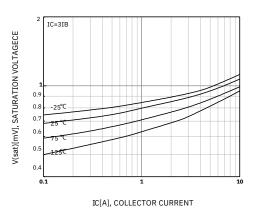


Figure 3. Base-Emitter Saturation Voltage

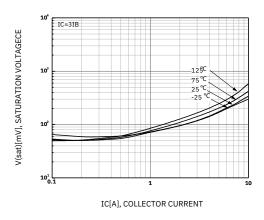


Figure 4. Collector-Emitter Saturation Voltage 1

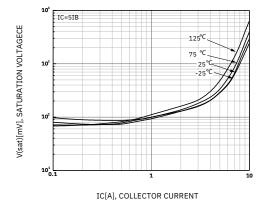


Figure 5. Collector-Emitter Saturation Voltage 2

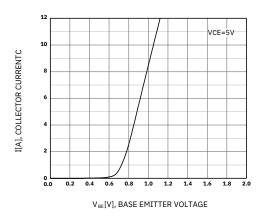


Figure 6. Base-Emitter On Voltage

©2000 Fairchild Semiconductor International Rev. A, February 2000

## **Typical Characteristics** (Continued)

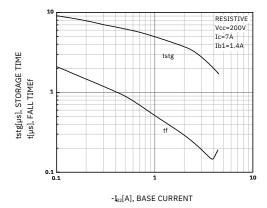


Figure 7. Switching Time

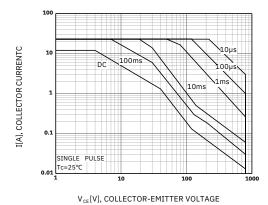


Figure 8. Safe Operating Area

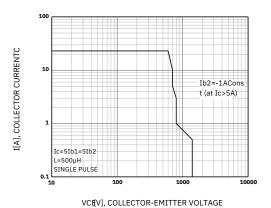


Figure 9. Reverse Bias Safe Operating Area

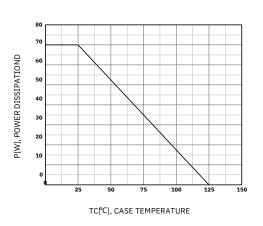
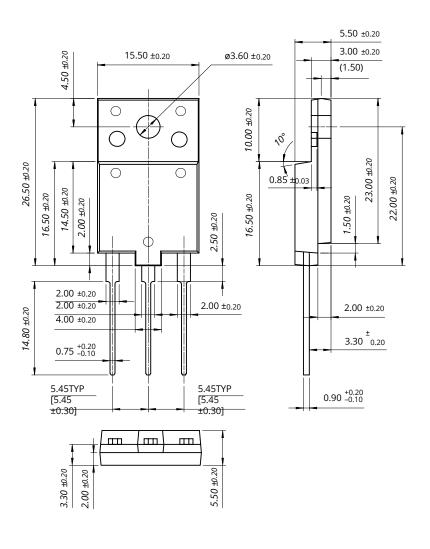


Figure 10. Power Derating

©2000 Fairchild Semiconductor International Rev. A, February 2000

# **Package Demensions**

# TO-3PF



Dimensions in Millimeters

#### **TRADEMARKS**

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

FACT™ QFET™ PACT Quiet Series™ QS™

FAST® Quiet Series™ FASTr™ SuperSOT™-3 SuperSOT™-6

#### **DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR INTERNATIONAL. As used herein:

1. Life support devices or systems are devices or systems2. A critical component is any component of a life support which, (a) are intended for surgical implant into the body, device or system whose failure to perform can be or (b) support or sustain life, or (c) whose failure to perform reasonably expected to cause the failure of the life support when properly used in accordance with instructions for usedevice or system, or to affect its safety or effectiveness. provided in the labeling, can be reasonably expected to result in significant injury to the user.

#### PRODUCT STATUS DEFINITIONS

### **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Des ig n	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

©2000 Fairchild Semiconductor International Rev. E